

SemiSouth Laboratories, Inc.



presented by Will Draper

Company Information:

SemiSouth Laboratories, Inc. develops and manufactures high-performance SiC epitaxy & electronic components.

Previous Relevant Accomplishments:

- 50 μm epitaxy w/ 8% thickness uniformity
- 120 μm epitaxy w/ 8% thickness uniformity
- $-N_d < 5x10^{14} \text{ cm}^{-3}$ doping concentration
- Up to 15 μm/hr growth rate



Area of Expertise:

- Growth of 100-200 μm epitaxy with proven 10 $\mu m/hr$ growth rate
- Advancement of epitaxy technology to achieve higher growth rates
- 2 PhD's + support staff (15+ yrs exp.)
- Multiple hot-wall reactors
- "Virtually" integrated epiwafer supplier through alliance with II-VI, Inc.

For more information please contact:

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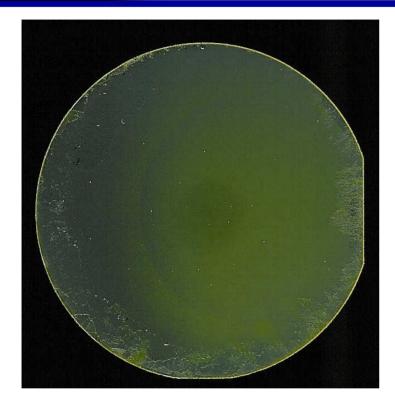
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Thick Epitaxy – 50 μm





Particle density: 1.3 cm⁻²

NOTE: grown on a mechanical

substrate of bad quality



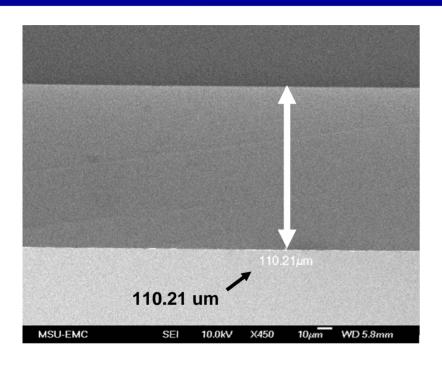


- Excellent surface morphology
- Thickness 49-50 μm
- Growth rate 10 μm/h
- Background ~ <u>5e14</u>
- Thickness uniformity < 8%



Thick Epitaxy – 120 μm





Average thickness: 119 μm

Growth rate: 15 μm/h

Uniformity: 7.6%

Particle density: 1.0 cm⁻²



